**TOSHIBA** 

Unit in mm

TOSHIBA INSULATED GATE BIPOLAR TRANSISTOR SILICON N CHANNEL IGBT

# GT50G321

### THE 4TH GENERATION

### **CURRENT RESONANCE INVERTER SWITCHING APPLICATIONS**

• FRD Included Between Emitter and Collector

• Enhancement-Mode

• High Speed :  $t_f = 0.30 \,\mu s$  (Typ.) (I<sub>C</sub> = 60 A)

• Low Saturation Voltage :  $V_{CE (sat)} = 1.8 \text{ V (Typ.)}$  ( $I_C = 60 \text{ A}$ )

## MAXIMUM RATINGS (Ta = 25°C)

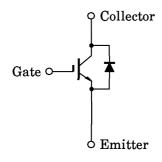
CHARACTERISTIC		SYMBOL	RATING	UNIT	
Collector-Emitter Voltage		$v_{CES}$	400	V	
Gate-Emitter Voltage		$v_{GES}$	±25	V	
Collector Current	DC	$I_{\mathbf{C}}$	50	A	
	1 ms	$I_{CP}$	100		
Emitter-Collector	DC	${ m I_F}$	15	A	
Foward Current	1 ms	$I_{ ext{FP}}$	30		
Collector Power Dissipation (Tc = 25°C)		PC	130	w	
Junction Temperature		$T_{j}$	150	°C	
Storage Temperature Range		$\mathrm{T_{stg}}$	-55~150	°C	

- 1. GAT
- 2. COLLECTOR (HEAT SINK)
- 3. EMITTER

JEDEC	_	
JEITA	_	
TOSHIBA	2-21F2C	

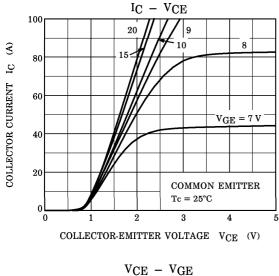
Weight: 9.75 g

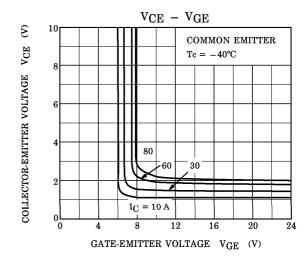
# **EQUIVALENT CIRCUIT**

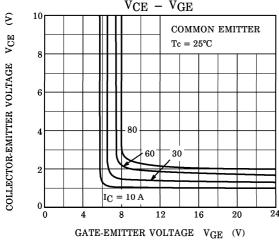


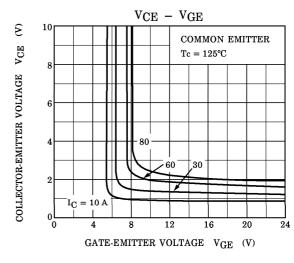
# ELECTRICAL CHARACTERISTICS (Ta = 25°C)

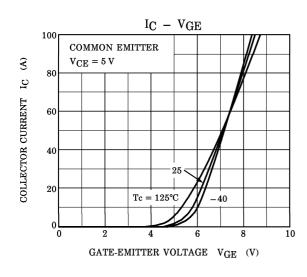
CHARA	CTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP	MAX.	UNIT
Gate Leakage	Current	$I_{ ext{GES}}$	$V_{GE} = \pm 25 \text{ V}, V_{CE} = 0$	_	_	±500	nA
Collector Cut-off Current		ICES	$V_{CE} = 400 \text{ V}, V_{GE} = 0$	_	_	1.0	mA
Gate-Emitter Cut-off Voltage		V <sub>GE</sub> (OFF)	$I_C = 60 \text{ mA}, V_{CE} = 5 \text{ V}$	3.0	_	6.0	V
Collector-Emi Voltage	tter Saturation	V <sub>CE</sub> (sat)	$I_{\rm C} = 60  { m A}, \; { m V}_{ m GE} = 15  { m V}$		1.8	2.5	v
Input Capacitance		Cies	$V_{CE} = 10 \text{ V}, V_{GE} = 0,$ f = 1 MHz	_	3900	_	pF
Switching Time	Rise Time	tr	15 V 39 Ω Σ Σ Σ Σ Σ Σ Σ Σ Σ Σ Σ Σ Σ Σ Σ Σ Σ Σ	_	0.33	_	μs
	Turn-on Time	ton		_	0.43	_	
	Fall Time	tf		_	0.30	0.40	
	Turn-off Time	toff		_	0.54	_	
Forward Voltage		$V_{\mathbf{F}}$	$I_{F} = 15 \text{ A}, V_{GE} = 0$	_	_	2.0	V
Reverse Recovery Time		t <sub>rr</sub>	$I_{F} = 15 \text{ A}, V_{GE} = 0$ di / dt = -100 A / $\mu$ s	_	_	0.2	μs
Thermal Resistance		R <sub>th (j-c)</sub>	IGBT	_	_	0.96	°C/W
Thermal Resistance		R <sub>th (j-c)</sub>	Diode	_	_	2.08	°C/W

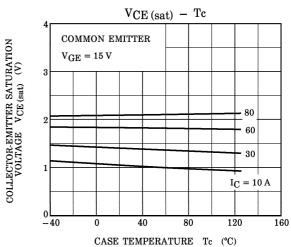


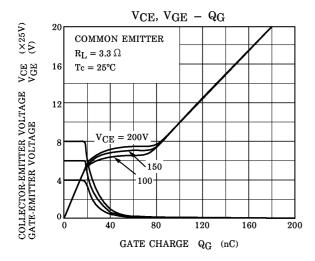


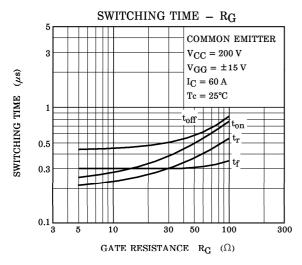


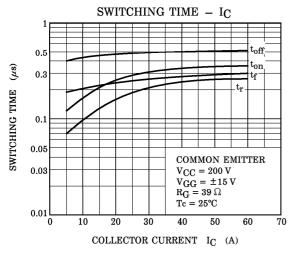


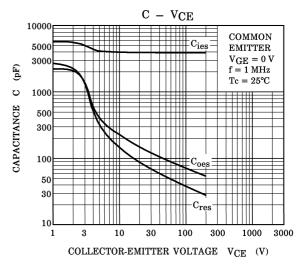


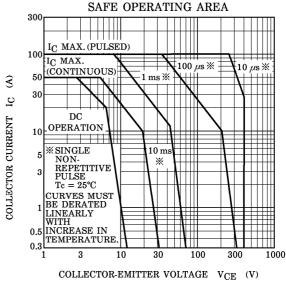






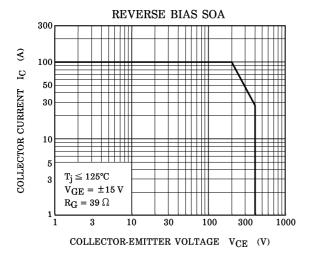


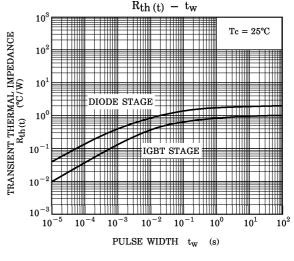


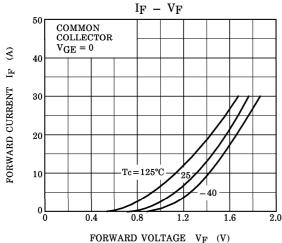


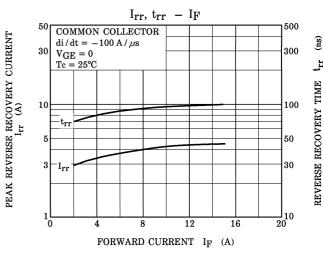
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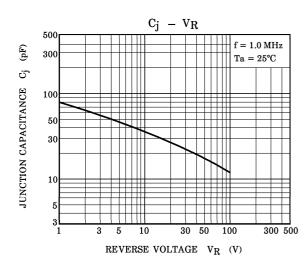
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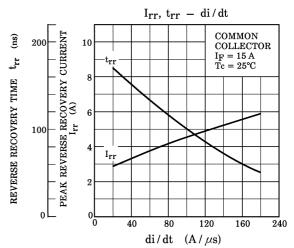












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